

Vishay Semiconductors

Standard Recovery Diodes (Stud Version), 400 A

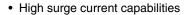
(Stud Version), 400 FEATURES

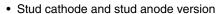


DO-205AB (DO-9)









- Standard JEDEC types
- · RoHS compliant
- Designed and qualified for industrial level



TYPICAL APPLICATIONS

PRODUCT SUMMARY				
I _{F(AV)}	400 A			

• Power supplies

Converters

- · Machine tool controls
- · High power drives

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
I _{F(AV)}		400	А	
	T _C	120	°C	
I _{F(RMS)}		630	А	
I _{FSM}	50 Hz	8250	۸	
	60 Hz	8640	А	
l ² t	50 Hz	340	kA ² s	
	60 Hz	311	KA-S	
V _{RRM}	Range	800 to 1600	V	
T _J		- 40 to 200	°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA	
	80	800	900		
400U(R)	120	1200	1300	15	
	160	1600	1700		

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400U(R) Series

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FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current at case temperature	I _{F(AV)}	180° conduction, half sine wave		400 120	A °C	
Maximum RMS forward current	le(puo)	DC at 110 °C	case temperatui	70	630	A
Waximum HiviS forward current	I _{F(RMS)}	DC at 110 °C case temperature				
		t = 10 ms	No voltage	Sinusoidal half wave, initial T _J = T _J maximum	8250	Α
Maximum peak, one cycle forward,		t = 8.3 ms	reapplied		8640	
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM}		6940	
		t = 8.3 ms	reapplied		7270	
	l ² t	t = 10 ms	No voltage		340	- kA ² s
Maximum I ² t for fusing		t = 8.3 ms	reapplied		311	
		t = 10 ms	100 % V _{RRM}		241	
		t = 8.3 ms	reapplied		220	
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied		3400	kA²√s	
Low level value of threshold voltage	V _{F(TO)1}	$(16.7 \% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		0.77	.,	
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		0.85	V	
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum		0.49	mΩ	
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		0.49	11177	
Maximum forward voltage drop	V_{FM}	$I_{pk} = 1500 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sinusoidal wave}$		1.62	V	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction operating and storage temperature range	T _J , T _{Stg}		- 40 to 200	°C	
Maximum thermal resistance, junction to case	R _{thJC}	UC operation		K/W	
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased 0		TVVV	
Maximum allowed mounting torque ± 10 %		Not lubricated threads	27	N · m	
Approximate weight			250	g	
Case style		See dimensions - link at the end of datasheet DO-205AB (DO-9)		3 (DO-9)	

△R _{thJC} CONDUCTION					
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.020	0.013			
120°	0.023	0.023			
90°	0.029	0.031	$T_J = T_J$ maximum	K/W	
60°	0.042	0.044			
30°	0.073	0.074			

Note

 $\bullet \ \ \, \text{The table above shows the increment of thermal resistance } \, R_{thJC} \, \text{when devices operate at different conduction angles than DC} \, \\$



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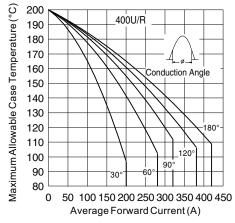


Fig. 1 - Current Ratings Characteristics

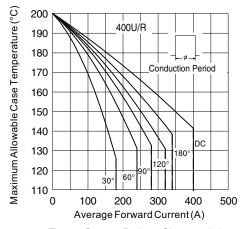


Fig. 2 - Current Ratings Characteristics

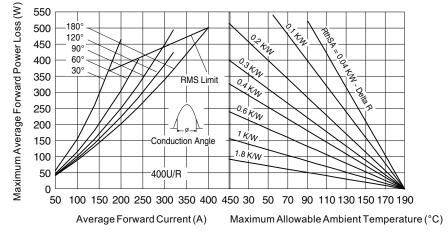


Fig. 3 - Forward Power Loss Characteristics

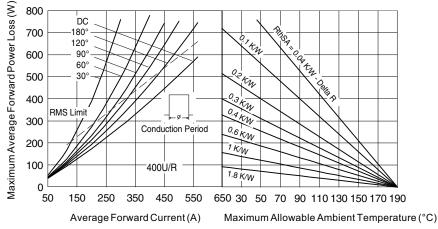


Fig. 4 - Forward Power Loss Characteristics

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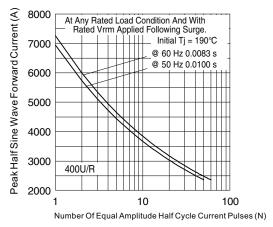


Fig. 5 - Maximum Non-Repetitive Surge Current

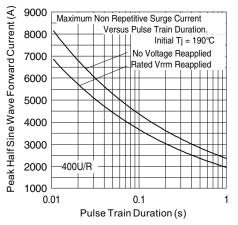


Fig. 6 - Maximum Non-Repetitive Surge Current

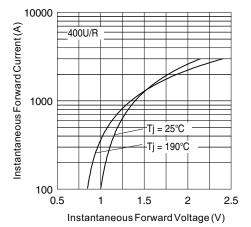


Fig. 7 - Forward Voltage Drop Characteristics

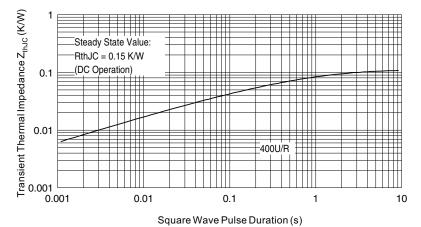
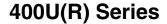


Fig. 8 - Thermal Impedance Z_{thJC} Characteristic



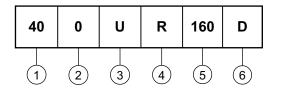


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ORDERING INFORMATION TABLE





1 - 40 = Essential part number

2 - 0 = Standard recovery device

U = Stud normal polarity (cathode to stud)

None = Stud normal polarity (cathode to stud)

• R = Stud reverse polarity (anode to stud)

5 - Voltage code x 10 = V_{RRM} (see Voltage Ratings table)

6 - Diffused diode

Note: For metric device M16 x 1.5 contact factory

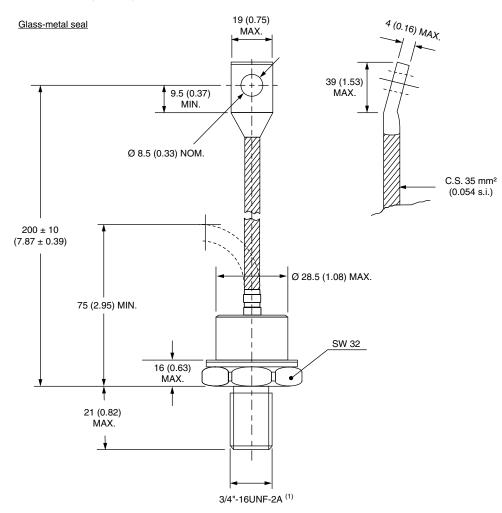
LINKS TO RELATED DOCUMENTS		
Dimensions	http://www.vishay.com/doc?95339	



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DO-205AB (DO-9) for 400U(R) Series

DIMENSIONS in millimeters (inches)



Note

• For metric device: M16 x 1.5 contact factory



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